

LM2904,LM358/LM358A

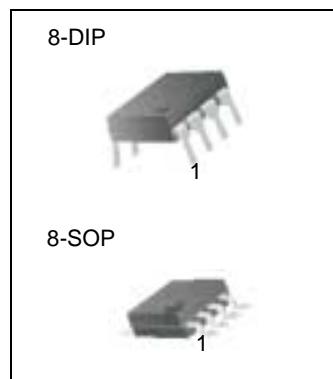
Dual Operational Amplifier

Features

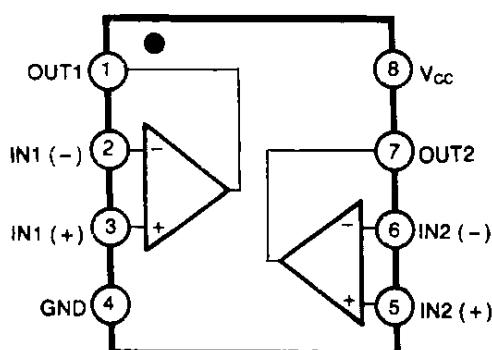
- Internally frequency compensated for unity gain
- Large DC voltage gain: 100dB
- Wide power supply range:
LM358/LM358A: 3V~32V (or $\pm 1.5V$ ~16V)
LM2904 : 3V~26V (or $\pm 1.5V$ ~13V)
- Input common-mode voltage range Includes ground
- Large output voltage swing: 0V DC to V_{cc} - 1.5V DC
- Power drain suitable for battery operation.

Description

The LM2904,LM358/LM358A consist of four independent, high gain, internally frequency compensated operational amplifiers which were designed specifically to operate from a single power supply over a wide range of voltage. Operation from split power supplies is also possible and the low power supply current drain is independent of the magnitude of the power Supply voltage. Application areas include transducer amplifier, DC gain blocks and all the conventional OP amp circuits which now can be easily implemented in single power Supply systems.

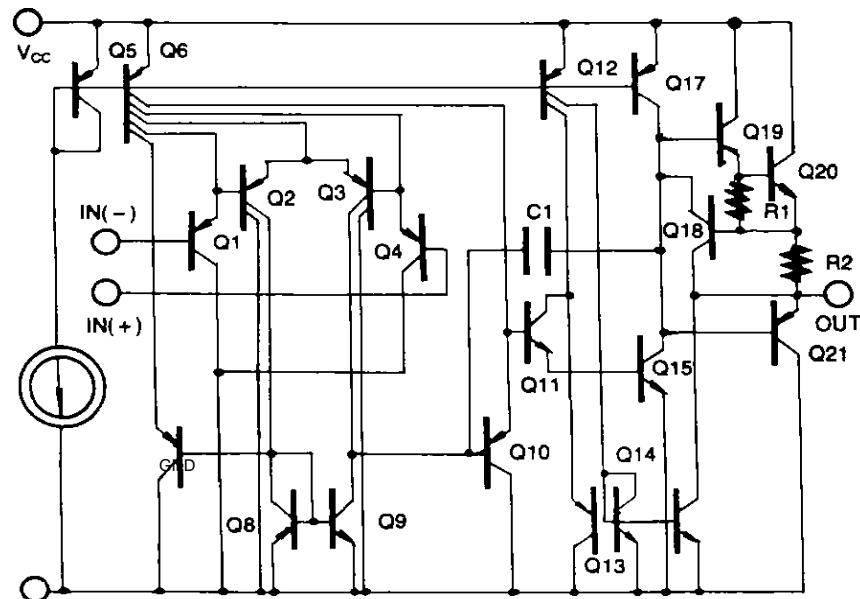


Internal Block Diagram



Schematic Diagram

(One section only)



Absolute Maximum Ratings

Parameter	Symbol	LM358/LM358A	LM2904	Unit
Supply Voltage	V _{CC}	±16 or 32	±13 or 26	V
Differential Input Voltage	V _{I(DIFF)}	32	26	V
Input Voltage	V _I	-0.3 to +32	-0.3 to +26	V
Output Short Circuit to GND V _{CC} ≤V, T _A = 25 °C(One Amp)	-	Continuous	Continuous	-
Operating Temperature Range	T _{OPR}	0 ~ + 70	-40 ~ + 85	°C
Storage Temperature Range	T _{STG}	-65 ~ + 150	-65 ~ + 150	°C

Electrical Characteristics

(V_{CC} = 5.0V, V_{EE} = GND, T = 25 °C, unless otherwise specified)

Parameter	Symbol	Conditions	LM358			LM2904			Unit
			Min.	Typ.	Max.	Min.	Typ.	Max.	
Input Offset Voltage	V _{IO}	V _{CM} = 0V to V _{CC} -1.5V V _{O(P)} = 1.4V, R _S = 0Ω	-	2.9	7.0	-	2.9	7.0	mV
Input Offset Current	I _{IO}	-	-	5	50	-	5	50	nA
Input Bias Current	I _{IBIAS}	-	-	45	250	-	45	250	nA
Input Voltage Range	V _{I(R)}	V _{CC} = 30V (LM2904, V _{CC} = 26V)	0	-	V _{CC} -1.5	0	-	V _{CC} -1.5	V
Supply Current	I _{CC}	R _L = ∞, V _{CC} = 30V (LM2902, V _{CC} = 26V)	-	0.8	2.0	-	0.8	2.0	mA
		R _L = ∞, over full temperature range	-	0.5	1.2	-	0.5	1.2	mA
Large Signal Voltage Gain	G _V	V _{CC} = 15V, R _L ≥ 2KΩ V _{O(P)} = 1V to 11V	25	100	-	25	100	-	V/mV
Output Voltage Swing	V _{O(H)}	V _{CC} = 30V R _L = 2KΩ	26	-	-	22	-	-	V
		V _{CC} = 26V R _L = 10KΩ for 2904	27	28	-	23	24	-	V
	V _{O(L)}	V _{CC} = 5V, R _L ≥ 10KΩ	-	5	20	-	5	100	mV
Common-Mode Rejection Ratio	CMRR	-	65	80	-	50	80	-	dB
Power Supply Rejection Ratio	PSRR	-	65	100	-	50	100	-	dB
Channel Separation	CS	f = 1KHz to 20KHz	-	120	-	-	120	-	dB
Short Circuit to GND	I _{SC}	-	-	40	60	-	40	60	mA
Output Current	I _{SOURCE}	V _{I(+)} = 1V, V _{I(-)} = 0V V _{CC} = 15V, V _{O(P)} = 2V	10	30	-	10	30	-	mA
		V _{I(+)} = 0V, V _{I(-)} = 1V V _{CC} = 15V, V _{O(P)} = 2V	10	15	-	10	15	-	mA
	I _{SINK}	V _{I(+)} = 0V, V _{I(-)} = 1V V _{CC} = 15V, V _{O(P)} = 200mA	12	100	-	-	-	-	μA
Differential Input Voltage	V _{I(DIFF)}	-	-	-	V _{CC}	-	-	V _{CC}	V

Electrical Characteristics

(VCC=5.0V, VEE=GND, unless otherwise specified)

The following specification apply over the range of $0^{\circ}\text{C} \leq T_A \leq +70^{\circ}\text{C}$ for the LM358 ; and the $-40^{\circ}\text{C} \leq T_A \leq +85^{\circ}\text{C}$ for the LM2904

Parameter	Symbol	Conditions	LM358			LM2904			Unit
			Min.	Typ.	Max.	Min.	Typ.	Max.	
Input Offset Voltage	V _{IO}	V _{CM} = 0V to V _{CC} = 1.5V V _{O(P)} = 1.4V, R _S = 0Ω	-	-	9.0	-	-	10.0	mV
Input Offset Voltage Drift	ΔV _{IO} /ΔT	R _S = 0Ω	-	7.0	-	-	7.0	-	μV/ °C
Input Offset Current	I _{IO}	-	-	-	150	-	45	200	nA
Input Offset Current Drift	ΔI _{IO} /ΔT	-	-	10	-	-	10	-	pA/ °C
Input Bias Current	I _{BIAS}	-	-	40	500	-	40	500	nA
Input Voltage Range	V _{I(R)}	V _{CC} = 30V (LM2904 , V _{CC} = 26V)	0	-	V _{cc} =2.0	0	-	V _{cc} =2.0	V
Large Signal Voltage Gain	G _V	V _{CC} = 15V, R _L ≥2.0KΩ V _{O(P)} = 1V to 11V	15	-	-	15	-	-	V/mV
Output Voltage Swing	V _{O(H)}	V _{CC} = 30V R _L = 2KΩ	26	-	-	26	-	-	V
		V _{CC} = 26V R _L = 10KΩ	27	28	-	27	28	-	V
	V _{O(L)}	V _{CC} = 5V, R _L ≥10KΩ	-	5	20	-	5	20	mV
Output Current	I _{SOURCE}	V _{I(+)} = 1V, V _{I(-)} = 0V V _{CC} = 15V, V _{O(P)} = 2V	10	30	-	10	30	-	mA
	I _{SINK}	V _{I(+)} = 0V, V _{I(-)} = 1V V _{CC} = 15V, V _{O(P)} = 2V	5	9	-	5	9	-	mA
Differential Input Voltage	V _{I(DIFF)}	-	-	-	V _{CC}	-	-	V _{CC}	V

Electrical Characteristics

(VCC = 5.0V. VEE=GND. TA=25 °C, unless otherwise specified)

Parameter	Symbol	Conditions	LM358A			Unit
			Mln.	Typ.	Max.	
Input Offset Voltage	V _{IO}	V _{CM} = 0V to V _{CC} = 1.5V V _{O(P)} = 1.4V, R _S = 0Ω	-	2.0	3.0	mV
Input Offset Current	I _{IO}	-	-	5	30	nA
Input Bias Current	I _{BIAS}	-	-	45	100	nA
Input Voltage Range	V _{I(R)}	V _{CC} = 30V	0	-	V _{CC} =1.5	V
Supply Current	I _{CC}	R _L = ∞, V _{CC} = 30V	-	0.8	2.0	mA
		R _L = ∞, over full temperature range	-	0.5	1.2	mA
Large Signal Voltage Gain	G _V	V _{CC} = 15V, R _L ≥ 2KΩ V _O = 1V to 11V	25	100	-	V/mV
Output Voltage Swing	V _{OH}	V _{CC} = 30V	R _L = 2KΩ	26	-	V
		V _{CC} = 26V for 2904	R _L = 10KΩ	27	28	V
	V _{O(L)}	V _{CC} = 5V, R _L ≥ 10KΩ	-	5	20	mV
Common-Mode Rejection Ratio	CMRR	-	65	85	-	dB
Power Supply Rejection Ratio	PSRR	-	65	100	-	dB
Channel Separation	CS	f = 1KHz to 20KHz	-	120	-	dB
Short Circuit to GND	I _{SC}	-	-	40	60	mA
Output Current	I _{SOURCE}	V _{I(+)} = 1V, V _{I(-)} = 0V V _{CC} = 15V, V _{O(P)} = 2V	20	30	-	mA
	I _{SINK}	V _{I(+)} = 1V, V _{I(-)} = 0V V _{CC} = 15V, V _{O(P)} = 2V	10	15	-	mA
		V _{in +} = 0V, V _{in -} = 1V V _{O(P)} = 200mV	12	100	-	μA
Differential Input Voltage	V _{I(DIFF)}	-	-	-	V _{CC}	V

Electrical Characteristics

(VCC = 5.0V, VEE = GND, unless otherwise specified)

The following specification apply over the range of $0^{\circ}\text{C} \leq T_A \leq +70^{\circ}\text{C}$ for the LM358A

Parameter	Symbol	Conditions	LM358A			Unit
			Min.	Typ.	Max.	
Input Offset Voltage	V _{IO}	V _{CM} = 0V to V _{CC} = 1.5V V _{O(P)} = 1.4V, R _S = 0Ω	-	-	5.0	mV
Input Offset Voltage Drift	ΔV _{IO} /ΔT	-	-	7.0	20	μV/°C
Input Offset Current	I _{IO}	-	-	-	75	nA
Input Offset Current Drift	ΔI _{IO} /ΔT	-	-	10	300	pA/°C
Input Bias Current	I _{BIAS}	-	-	40	200	nA
Input Common-Mode Voltage Range	V _{I(R)}	V _{CC} = 30V	0	-	V _{cc} =2.0	V
Output Voltage Swing	V _{O(H)}	V _{CC} = 30V R _L = 2KΩ	26	-	-	V
		V _{CC} = 30V R _L = 10KΩ	27	28	-	V
	V _{O(L)}	V _{CC} = 5V, R _L ≥ 10KΩ	-	5	20	mV
Large Signal Voltage Gain	G _V	V _{CC} = 15V, R _L ≥ 2.0KΩ V _{O(P)} = 1V to 11V	15	-	-	V/mV
Output Current	I _{SOURCE}	V _{I(+)} = 1V, V _{I(-)} = 0V V _{CC} = 15V, V _{O(P)} = 2V	10	30	-	mA
	I _{SINK}	V _{I(+)} = 1V, V _{I(-)} = 0V V _{CC} = 15V, V _{O(P)} = 2V	5	9	-	mA
Differential Input Voltage	V _{I(DIFF)}	-	-	-	V _{CC}	V

Typical Performance Characteristics

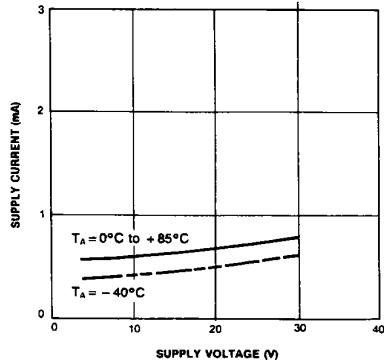


Figure 1. Supply Current vs Supply Voltage

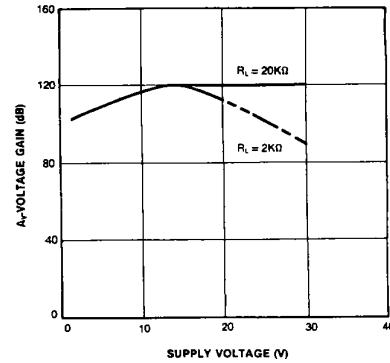


Figure 2. Voltage Gain vs Supply Voltage

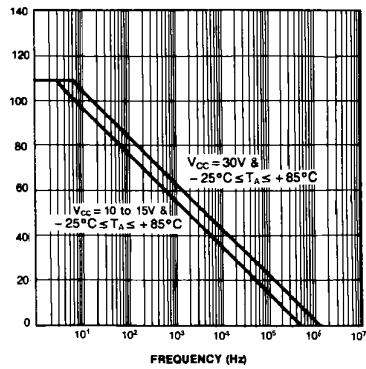


Figure 3. Open Loop Frequency Response

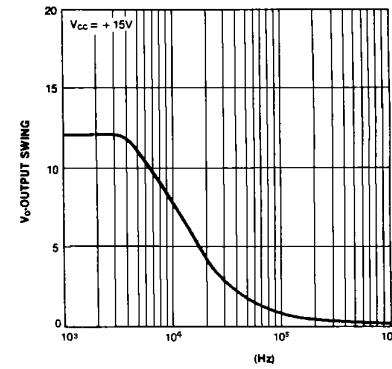


Figure 4. Large Signal Output Swing vs Frequency

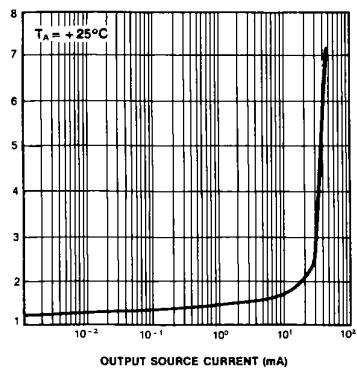


Figure 5. Output Characteristics vs Current Sourcing

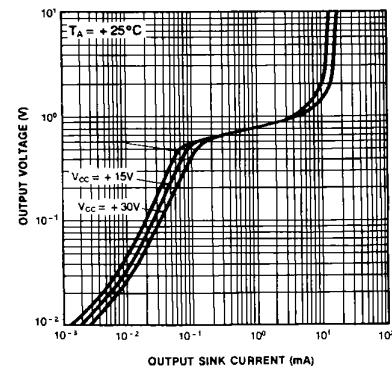


Figure 6. Output Characteristics vs Current Sinking

Typical Performance Characteristics (continued)

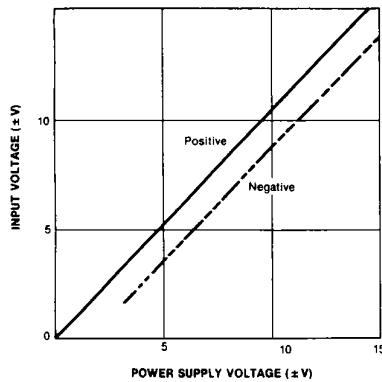


Figure 7. Input Voltage Range vs Supply Voltage

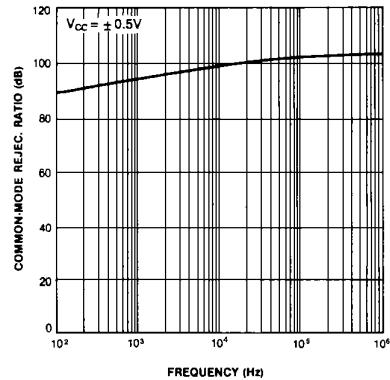


Figure 8. Common-Mode Rejection Ratio

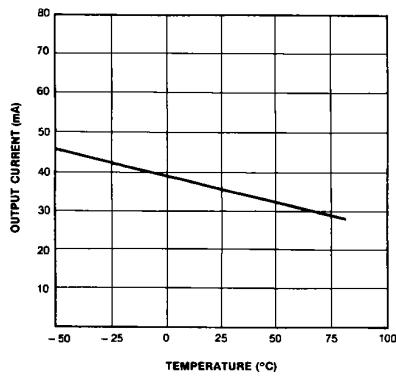


Figure 9. Current Limiting vs Temperature

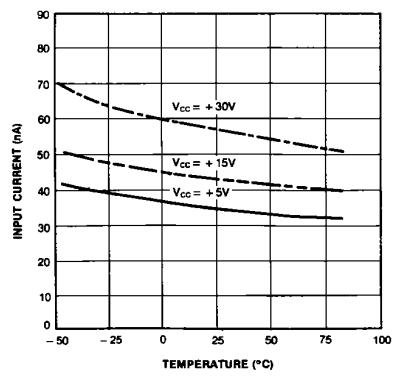


Figure 10. Input Current vs Temperature

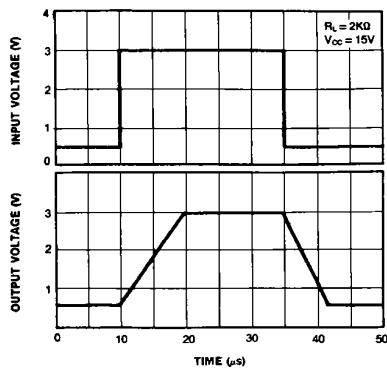


Figure 11. Voltage Follower Pulse Response

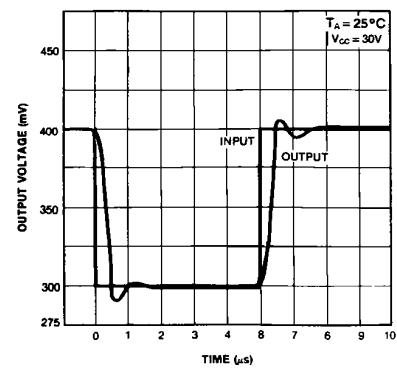
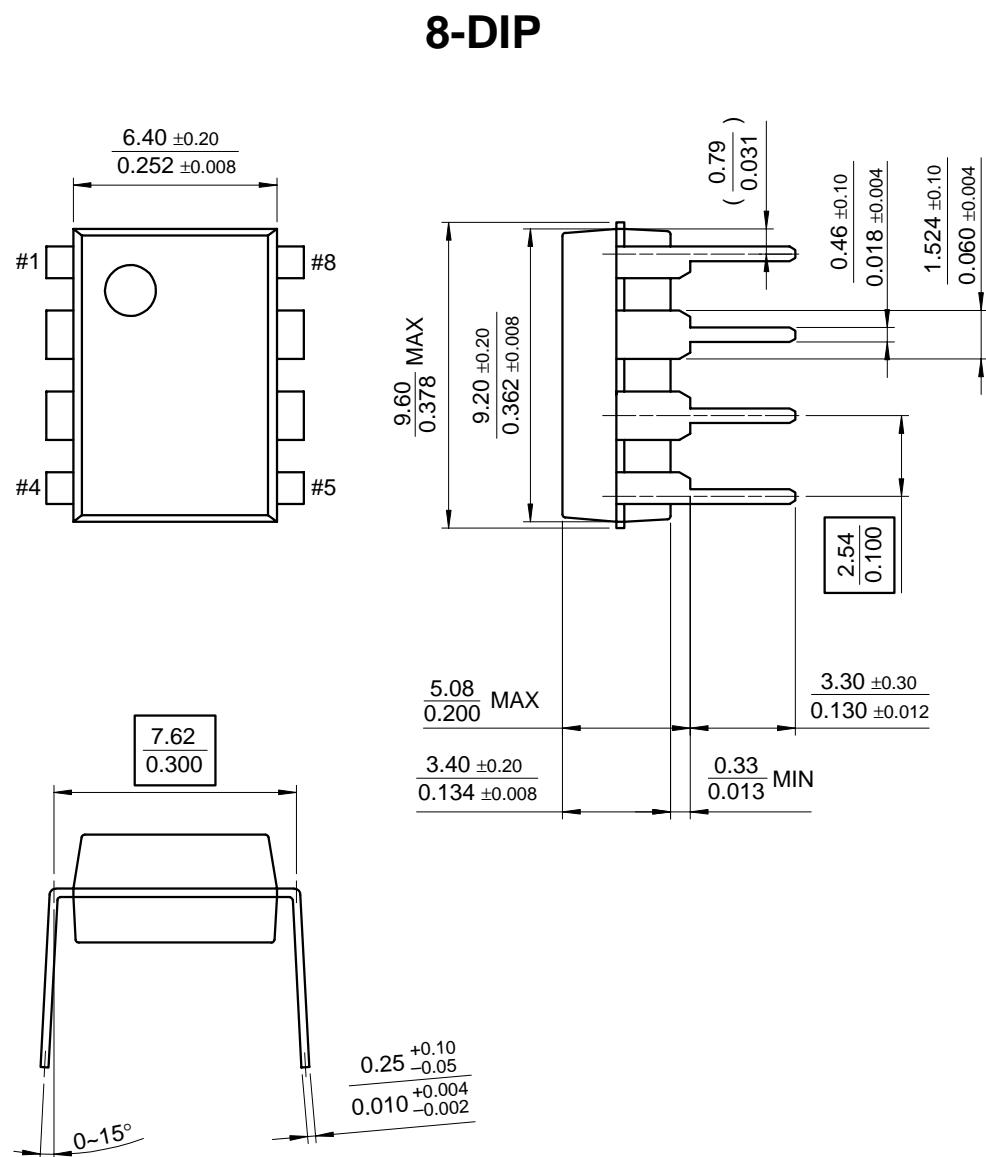


Figure 12. Voltage Follower Pulse Response (Small Signal)

Mechanical Dimensions

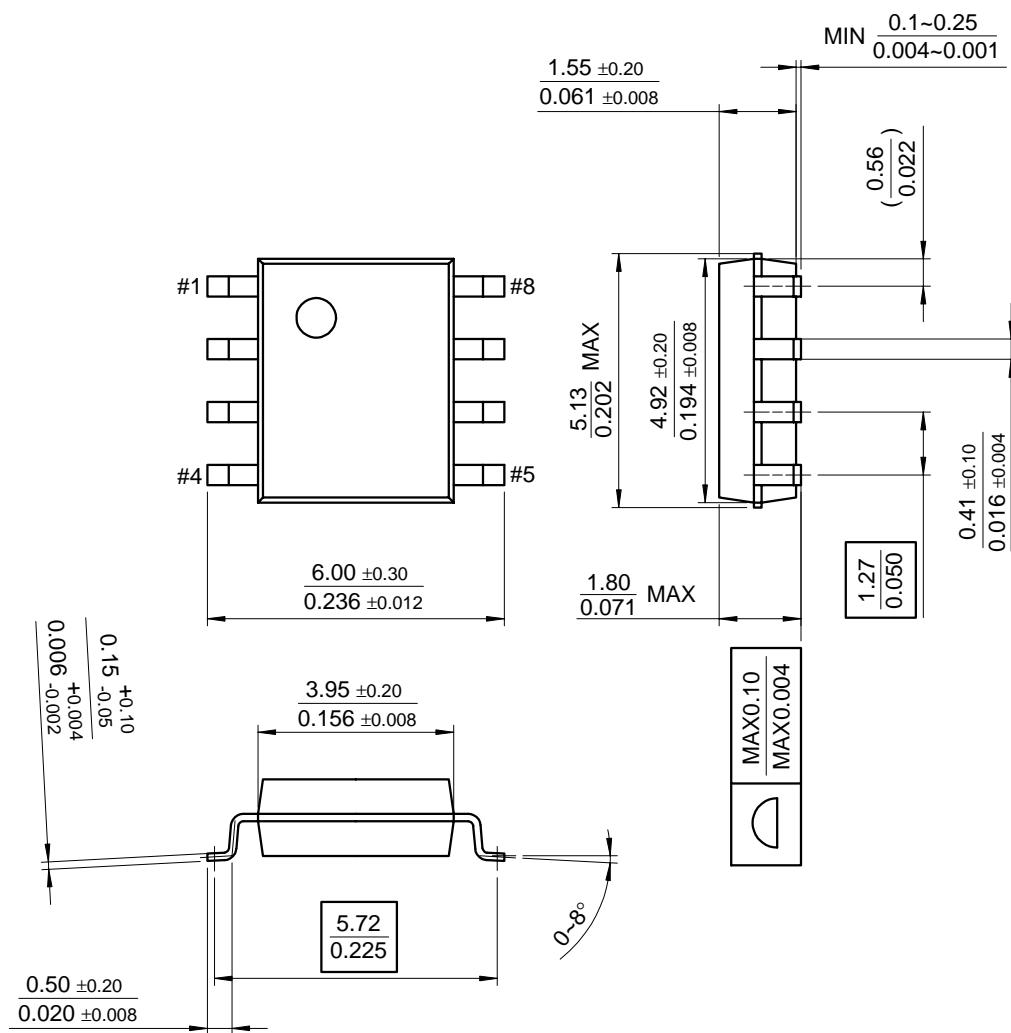
Package



Mechanical Dimensions (Continued)

Package

8-SOP



Ordering Information

Product Number	Package	Operating Temperature
LM358N	8-DIP	0 ~ + 70°C
LM358AN		
LM358M	8 SOP	-40 ~ + 85 °C
LM358AM		
LM2904N	8-DIP	-40 ~ + 85 °C
LM2904M	8 SOP	

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.